NSN 5962-01-357-1207

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-357-1207
Overall Length:
Between 1.181 inches and 1.211 inches
Overall Height:
Between 0.270 inches and 0.290 inches
Body Length:
Between 1.181 inches and 1.211 inches
Body Width:
Between 0.246 inches and 0.270 inches
Body Height:
0.130 inches
Operating Tempurature Range:
+0.0/+75.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Test set, guided missle system
Features Provided:
Bidirectional and w/clock and w/enable and w/disable and monolithic and 3-state output and programmable
Inclosure Material:
Plastic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistan transistan la sia
Transistor-transistor logic
Input Circuit Pattern:
-
Input Circuit Pattern:
Input Circuit Pattern: 20 input
Input Circuit Pattern: 20 input Current Rating Per Characteristic:
Input Circuit Pattern: 20 input Current Rating Per Characteristic: 105.00 milliamperes reverse current, dc absolute
Input Circuit Pattern: 20 input Current Rating Per Characteristic: 105.00 milliamperes reverse current, dc absolute Terminal Surface Treatment:
Input Circuit Pattern: 20 input Current Rating Per Characteristic: 105.00 milliamperes reverse current, dc absolute Terminal Surface Treatment: Solder
Input Circuit Pattern: 20 input Current Rating Per Characteristic: 105.00 milliamperes reverse current, dc absolute Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic:
Input Circuit Pattern: 20 input Current Rating Per Characteristic: 105.00 milliamperes reverse current, dc absolute Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source
Input Circuit Pattern: 20 input Current Rating Per Characteristic: 105.00 milliamperes reverse current, dc absolute Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source Memory Device Type:
Input Circuit Pattern: 20 input Current Rating Per Characteristic: 105.00 milliamperes reverse current, dc absolute Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source Memory Device Type: Pal
Input Circuit Pattern: 20 input Current Rating Per Characteristic: 105.00 milliamperes reverse current, dc absolute Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source Memory Device Type: Pal Terminal Type And Quantity:
Input Circuit Pattern: 20 input Current Rating Per Characteristic: 105.00 milliamperes reverse current, dc absolute Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source Memory Device Type: Pal Terminal Type And Quantity: 24 printed circuit
Input Circuit Pattern: 20 input Current Rating Per Characteristic: 105.00 milliamperes reverse current, dc absolute Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source Memory Device Type: Pal Terminal Type And Quantity: 24 printed circuit Shelf Life:

Demilitarization:

Yes - demil/mli

NSN 5962-01-357-1207

Memory Microcircuit - Page 2 of 2



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